256K (32K x 8)

5-Volt Only

CMOS

PEROM

Features

- Fast Read Access Time 90 ns
- **Five-Volt-Only Reprogramming**
- Page Program Operation

Single Cycle Reprogram (Erase and Program) Internal Address and Data Latches for 64 Bytes

Fast Program Cycle Times

Page (64 Byte) Program Time - 10 ms

Chip Erase Time - 10 ms

- Internal Program Control Timer
 - Low Power Dissipation

80 mA Active Current

300 µA CMOS Standby Current

- Hardware and Software Data Protection
- DATA Polling for End of Program Detection
- High Reliability CMOS Technology 1000 Erase/Program Cycles

10 Year Data Retention

- Single 5 V ± 10% Supply
- CMOS and TTL Compatible Inputs and Outputs
- Full Military, Commercial, and Industrial Temperature Ranges
- Pin-Compatible with 29C010 and 29C512 for Easy System Upgrades

Description

The AT29C257 is a five-volt-only in-system Programmable and Erasable Read Only Memory (PEROM), Its 256K of memory is organized as 32,768 words by 8 bits. Manufactured with Atmel's advanced nonvolatile CMOS technology, the device offers access times to 90 ns with power dissipation of just 440 mW. When the device is deselected, the CMOS standby current is less than 300 u.A.

To allow for simple in-system reprogrammability, the AT29C257 does not require high input voltages for programming. Five-volt-only commands determine the operation of the device. Reading data out of the device is similar to reading from a static RAM. Reprogramming the AT29C257 is performed on a page basis; 64 bytes of data are loaded into the device and then simultaneously programmed. The contents of the entire device may be erased by using a sixbyte software code (although erasure before programming is not needed).

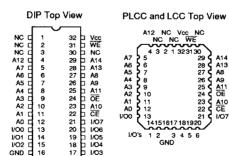
During a reprogram cycle, the address locations and 64 bytes of data are internally latched, freeing the address and data bus for other operations. Following the initiation of a program cycle, the device will automatically erase the page and then program the latched data using an internal control timer. The end of a program cycle can be detected by DATA polling of I/O7. Once the end of a program cycle has been detected a new access for a read, program or chip erase can begin.

Pin Configurations

Pin Name	Function
A0 - A14	Addresses
CE	Chip Enable
ŌĒ	Output Enable
WE	Write Enable
1/00 - 1/07	Data Inputs/Outputs
NC	No Connect

Notes:

- 1. PLCC package pin 30 is a DON'T CONNECT.
- 2. To upgrade to the 1-Mbit 29C010, pin 3 is A15 and pin 2 is A16.

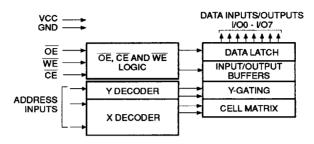


3-27

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Block Diagram



Device Operation

READ: The AT29C257 is accessed like a static RAM. When \overline{CE} and \overline{OE} are low and \overline{WE} is high, the data stored at the memory location determined by the address pins is asserted on the outputs. The outputs are put in the high impedance state whenever \overline{CE} or \overline{OE} is high. This dual-line control gives designers flexibility in preventing bus contention.

BYTE LOAD: A byte load is performed by applying a low pulse on the \overline{WE} or \overline{CE} input with \overline{CE} or \overline{WE} low (respectively) and \overline{OE} high. The address is latched on the falling edge of \overline{CE} or \overline{WE} , whichever occurs last. The data is latched by the first rising edge of \overline{CE} or \overline{WE} . Byte loads are used to enter the 64 bytes of a page to be programmed or the software codes for data protection and chip erasure.

PROGRAM: The device is reprogrammed on a page basis. If a byte of data within a page is to be changed, data for the entire page must be loaded into the device. Any byte that is not loaded during the programming of its page will be erased to read FFh. Once the bytes of a page are loaded into the device, they are simultaneously programmed during the internal programming period. After the first data byte has been loaded into the device, successive bytes are entered in the same manner. Each new byte to be programmed must have its high to low transition on WE (or \overline{CE}) within 150 µs of the low to high transition of \overline{WE} (or CE) of the preceding byte. If a high to low transition is not detected within 150 µs of the last low to high transition, the load period will end and the internal programming period will start. A6 to A14 specify the page address. The page address must be valid during each high to low transition of \overline{WE} (or \overline{CE}). A0 to A5 specify the byte address within the page. The bytes may be loaded in any order; sequential loading is not required.

SOFTWARE DATA PROTECTION: A software controlled data protection feature is available on the AT29C257. Once the software protection is enabled a software algorithm must be issued to the device before a program may be performed. The software protection feature may be enabled or disabled by the

user; when shipped from Atmel, the software data protection feature is disabled. To enable the software data protection, a series of three program commands to specific addresses with specific data must be performed. After the software data protection is enabled the same three program commands must begin each program cycle in order for the programs to occur. All software program commands must obey the page program timing specifications. Once set, the software data protection feature remains active unless its disable command is issued. Power transitions will not reset the software data protection feature, however the software feature will guard against inadvertent program cycles during power transitions.

Once set, software data protection will remain active unless the disable command sequence is issued.

After setting SDP, any attempt to write to the device without the three-byte command sequence will start the internal write timers. No data will be written to the device; however, for the duration of two, a read operation will effectively be a polling operation.

After the software data protection's three-byte command code is given, a byte load is performed by applying a low pulse on the \overline{WE} or \overline{CE} input with \overline{CE} or \overline{WE} low (respectively) and \overline{OE} high. The address is latched on the falling edge of \overline{CE} or \overline{WE} , whichever occurs last. The data is latched by the first rising edge of \overline{CE} or \overline{WE} .

The 64 bytes of data must be loaded into each sector. Any byte that is not loaded during the programming of its sector will be erased to read FFh. Once the bytes of a sector are loaded into the device, they are simultaneously programmed during the internal programming period. After the first data byte has been loaded into the device, successive bytes are entered in the same manner. Each new byte to be programmed must have its high to low transition on \overline{WE} (or \overline{CE}) within 150 μs of the low to high transition is not detected within 150 μs of the last low to high

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AT29C257

1074177 0005189 574

3-28

Device Operation (Continued)

transition, the load period will end and the internal programming period will start. A6 to A14 specify the sector address. The sector address must be valid during each high to low transition of \overline{WE} (or \overline{CE}). A0 to A5 specify the byte address within the sector. The bytes may be loaded in any order; sequential loading is not required.

HARDWARE DATA PROTECTION: Hardware features protect against inadvertent programs to the AT29C257 in the following ways: (a) V_{CC} sense—if V_{CC} is below 3.8 V (typical), the program function is inhibited. (b) V_{CC} power on delay—once V_{CC} has reached the V_{CC} sense level, the device will automatically time out 5 ms (typical) before programming. (c) Program inhibit—holding any one of \overline{OE} low, \overline{CE} high or \overline{WE} high inhibits program cycles. (d) Noise filter—pulses of less than 15 ns (typical) on the \overline{WE} or \overline{CE} inputs will not initiate a program cycle.

PRODUCT IDENTIFICATION: The product identification mode identifies the device and manufacturer and may be ac-

cessed by a hardware or software operation. For details, see Operating Modes or Software Product Identification.

DATA POLLING: The AT29C257 features DATA polling to indicate the end of a program cycle. During a program cycle an attempted read of the last byte loaded will result in the complement of the loaded data on I/O7. Once the program cycle has been completed, true data is valid on all outputs and the next cycle may begin. DATA polling may begin at any time during the program cycle.

TOGGLE BIT: In addition to DATA polling the AT29C257 provides another method for determining the end of a program or erase cycle. During a program or erase operation, successive attempts to read data from the device will result in I/O6 toggling between one and zero. Once the program cycle has completed, I/O6 will stop toggling and valid data will be read. Examining the toggle bit may begin at any time during a program cycle.

OPTIONAL CHIP ERASE MODES: The entire device may be erased by either using a six-byte software code or high voltage. For details, please contact Atmel.

Absolute Maximum Ratings*

Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
All Input Voltages (including N.C. Pins) with Respect to Ground0.6 V to +6.25 V
All Output Voltages with Respect to Ground0.6 V to Vcc +0.6 V
Voltage on $\overline{\text{OE}}$ with Respect to Ground0.6 V to +13.5 V

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Pin Capacitance $(f = 1 \text{ MHz}, T = 25^{\circ}\text{C})^{(1)}$

	Тур	Max	Units	Conditions
Cin	4	6	pF	$V_{IN} = 0 V$
Cout	8	12	pF	Vout = 0 V

Note: 1. This parameter is characterized and is not 100% tested.



3-29

1074177 0005190 296





D.C. and A.C. Operating Range

		AT29C257-90	AT29C257-12	AT29C257-15	AT29C257-20	AT29C257-25
Operating	Com.	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C
Temperature (Case)	ind.		-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C
Vcc Power Supp	ly	5 V ± 10%	5 V ± 10%	5 V ± 10%	5 V ± 10%	5 V ± 10%

Operating Modes

Mode	CE	ŌĒ	WE	Al	1/0
Read	VIL	VIL	ViH	Ai	Dout
Program ⁽²⁾	VIL	VIH	VIL	Ai	DIN
5V Chip Erase	VIL	ViH	VIL	Ai	
Standby/Write Inhibit	VIH	X ⁽¹⁾	X	X	High Z
Write Inhibit	Х	х	ViH		
Write Inhibit	Х	VIL	Х		
Output Disable	Х	Vін	X		High Z
High Voltage Chip Erase	VIL	VH ⁽³⁾	VIL	X	High Z
Product Identification	V.,	V.	Vзн	A1-A14 = V _{IL} , A9 = V _H , A0 = V _{IL}	Manufacturer Code ⁽⁴⁾
Product identification	ViL	VIL	VIH	A1-A14 = V _{IL} , A9 = V _H , A0 = V _{IH}	Device Code ⁽⁴⁾

Notes: 1. X can be V_{IL} or V_{IH}.

2. Refer to A.C. Programming Waveforms.

3. $V_H = 12.0 \text{ V} \pm 0.5 \text{ V}$.

4. Manufacturer Code: 1F, Device Code: DC

D.C. Characteristics

Symbol	Parameter	Condition	Min	Max	Units
lu .	Input Load Current	V _{IN} = 0 V to V _{CC}		10	μΑ
ILO	Output Leakage Current	V _{I/O} = 0 V to V _{CC}		10	μΑ
Is _{B1}	Vcc Standby Current CMOS	CE = Vcc-0.3V to Vcc		300	μΑ
ISB2	Vcc Standby Current TTL	CE = 2.0 V to Vcc		3	mA
lcc	Vcc Active Current	f= 5 MHz; lout = 0 mA		50	mA
ViL	Input Low Voltage			0.8	V
ViH	Input High Voltage		2.0		٧
Vol	Output Low Voltage	loL ≠ 2.1 mA	•	.45	٧
V _{OH1}	Output High Voltage	loн = -400 μA	2.4		٧
VOH2	Output High Voltage CMOS	loн = -100 μA; Vcc = 4.5V	4.2		V

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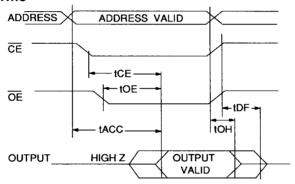
3-30

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A.C. Read Characteristics

	, , , ,		AT29C257- 90 12 AT29C257- 15		AT29C257- AT29C25							
Symbol	Parameter	Min	Max	Min	Мах	Min	Max	Min	Мах	Min	Max	Units
tacc	Address to Output Delay		90		120		150		200		250	ns
tce (1)	CE to Output Delay		90		120		150		200		250	ns
toE (2)	OE to Output Delay	0	40	0	50	0	70	0	80	0	100	ns
t _{DF} (3,4)	CE or OE to Output Float	0	40	0	40	0	50	0	55	0	60	ns
tон	Output Hold from OE, CE or Address, whichever occurred first	0		0		0		0		0		ns

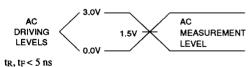
A.C. Read Waveforms



Notes

- 1. $\overline{\text{CE}}$ may be delayed up to t_{ACC} t_{CE} after the address transition without impact on t_{ACC} .
- OE may be delayed up to tCE tOE after the falling edge of CE without impact on tCE or by tACC - tOE after an address change without impact on tACC.
- 3. t_{DF} is specified from \overline{OE} or \overline{CE} whichever occurs first ($C_L = 5$ pF).
- 4. This parameter is characterized and is not 100% tested.

Input Test Waveforms and Measurement Level



Output Test Load





3-31

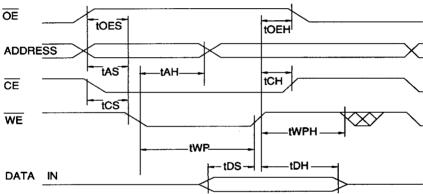
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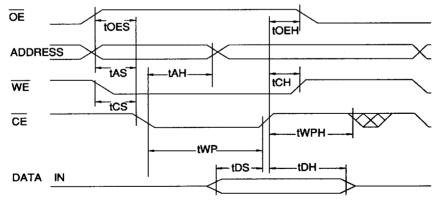
A.C. Byte Load Characteristics

Symbol	Parameter	Min	Max	Units
tas, toes	Address, OE Set-up Time	0		ns
t AH	Address Hold Time	50		ns
tcs	Chip Select Set-up Time	0		ns
tсн	Chip Select Hold Time	0		ns
twp	Write Pulse Width (WE or CE)	90		ns
tos	Data Set-up Time	50		ns
tDH,tOEH	Data, OE Hold Time	0		ns
twc	Write Cycle Time		10	ms

A.C. Byte Load Waveforms- WE Controlled



A.C. Byte Load Waveforms- CE Controlled



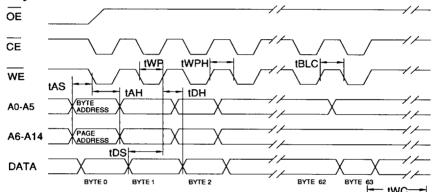
3-32 AT29C257

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Program Cycle Characteristics

Symbol	Parameter	Min	Max	Units
twc	Write Cycle Time		10	ms
tas	Address Set-up Time	0		ns
tah	Address Hold Time	50		ns
tos	Data Set-up Time	50		ns
ton	Data Hold Time	0		ns
twp	Write Pulse Width	120		ns
t BLC	Byte Load Cycle Time		150	μs
twpH	Write Pulse Width High	100		ns

Program Cycle Waveforms



Notes:

A6 through A14 must specify the page address during each high to \underline{low} transition of \overline{WE} (or \overline{CE}).

 \overline{OE} must be high when \overline{WE} and \overline{CE} are both low.

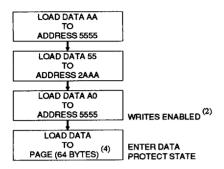
All bytes that are not loaded within the page being programmed

will be erased to FF.





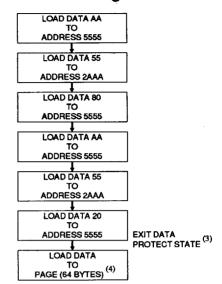
Software Data Protection Enable Algorithm (1)



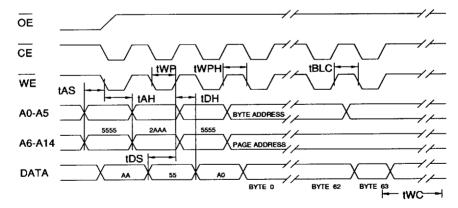
Notes for software program code:

- Data Format: I/O7 I/O0 (Hex);
 Address Format: A14 A0 (Hex).
- 2. Data Protect state will be activated at end of program cycle.
- 3. Data Protect state will be deactivated at end of program period.
- 4. 64 bytes of data must be loaded.

Software Data Protection Disable Algorithm (1)



Software Protected Program Cycle Waveform



- Notes: 1. A6 through A14 must specify the page address during each high to low transition of WE (or CE) after the software code has been entered.
 - 2. \overline{OE} must be high when \overline{WE} and \overline{CE} are both low.
 - All bytes that are not loaded within the page being programmed will be erased to FF.

AT29C257

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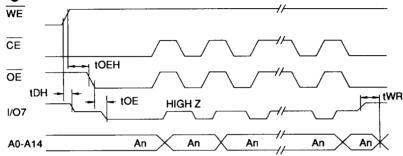
3-34

Data Polling Characteristics⁽¹⁾

Symbol	Parameter	Min	Тур	Max	Units
t DH	Data Hold Time	. 0			ns
toeh	OE Hold Time	10			ns
toe	OE to Output Delay			100	ns
twr	Write Recovery Time	0			ns

Note: 1. These parameters are characterized and not 100% tested.

Data Polling Waveforms

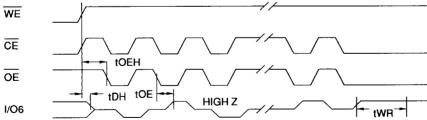


Toggle Bit Characteristics(1)

Symbol	Parameter	Min	Тур	Max	Units
tрн	Data Hold Time	0			ns
t OEH	OE Hold Time	10			ns
t OE	OE to Output Delay			100	ns
t OEHP	OE High Pulse	150			ns
twa	Write Recovery Time	0			ns

Note: 1. These parameters are characterized and not 100% tested.

Toggle Bit Waveforms



Notes:

- 1. Toggling either \overline{OE} or \overline{CE} or both \overline{OE} and \overline{CE} will operate toggle bit.
- 2. Beginning and ending state of I/O6 will vary.
- 3. Any address location may be used but the address should not vary.

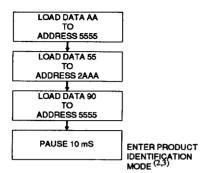


3-35

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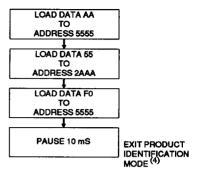
Software Product Identification Entry (1)



Notes for software product identification:

- 1. Data Format: I/O7 I/O0 (Hex); Address Format: A14 - A0 (Hex).
- A1 A14 = V_{II}.
 Manufacture Code is read for A0 = V_{II}.
 Device Code is read for A0 = V_{II}.
- The device does not remain in identification mode if powered down.
- 4. The device returns to standard operation mode.

Software Product Identification Exit

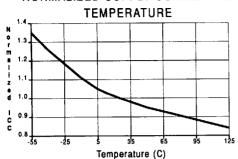


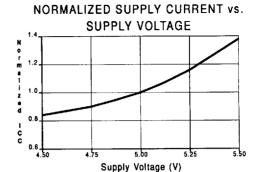
AT29C257

3-36

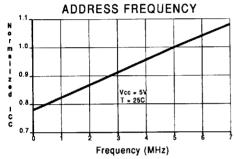
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NORMALIZED SUPPLY CURRENT vs.





NORMALIZED SUPPLY CURRENT vs.



<u>AIMEL</u>

3-37



Ordering Information

tacc	lcc	(mA)			
(ns) Active Standby		Standby	Ordering Code Package		Operation Range
90	80	0.3	AT29C257-90DC AT29C257-90JC AT29C257-90PC	32D6 32J 32P6	Commercial (0° to 70°C)
120	80	0.3	AT29C257-12DC AT29C257-12JC AT29C257-12LC AT29C257-12PC	32D6 32J 32L 32P6	Commercial (0° to 70°C)
			AT29C257-12DI AT29C257-12JI AT29C257-12LI AT29C257-12PI	32D6 32J 32L 32P6	Industrial (-40° to 85°C)
150	50 80 0.3	0.3	AT29C257-15DC AT29C257-15JC AT29C257-15LC AT29C257-15PC	32D6 32J 32L 32P6	Commercial (0° to 70°C)
			AT29C257-15DI AT29C257-15JI AT29C257-15LI AT29C257-15PI	32D6 32J 32L 32P6	Industrial (-40° to 85°C)
200	80	0.3	AT29C257-20DC AT29C257-20JC AT29C257-20LC AT29C257-20PC	32D6 32J 32L 32P6	Commercial (0° to 70°C)
			AT29C257-20DI AT29C257-20JI AT29C257-20LI AT29C257-20PI	32D6 32J 32L 32P6	Industrial (-40° to 85°C)
250	80	0.3	AT29C257-25DC AT29C257-25JC AT29C257-25LC AT29C257-25PC	32D6 32J 32L 32P6	Commercial (0° to 70°C)
250	80	0.3	AT29C257-25DI AT29C257-25JI AT29C257-25LI AT29C257-25PI	32D6 32J 32L 32P6	Industrial (-40° to 85°C)

Package Type		
32D6	32 Lead, 0.600" Wide, Non-Windowed, Ceramic Dual Inline Package (Cerdip)	
32J	32 Lead, Plastic J-Leaded Chip Carrier (PLCC)	
32L	32 Pad, Non-Windowed, Ceramic Leadless Chip Carrier (LCC)	
32P6	32 Lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)	

3-38

AT29C257

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